Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Ceramic or glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.092 inch	es and 0.104 inches
Mounting Method:	
Terminal	
Features Provided	:
Burn in	
Cubic Measure:	
0.010 cubic inches	
Semiconductor Ma	iterial:
Silicon	
Voltage Rating In V	/olts Per Characteristic:
35.0 breakdown vo	Itage, dc
Current Rating Per	Characteristic:
100.00 milliamperes	s forward current, total rms peak
Capacitance Ratin	g In Picofarads:
52.5	
Maximum Operatir	ng Tempurature Per Measurement Point:
150.0 degrees celsi	us ambient air
Terminal Type And	I Quantity:
2 uninsulated wire le	ead
Specification Data	:
80063-a3012733 m	anufacturers source control
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	